NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3050 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =50A

 $R_{DS(ON)}$ < 11m Ω @ V_{GS} =10V

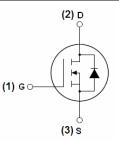
 $R_{DS(ON)}$ < 16m Ω @ V_{GS} =4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



Schematic diagram



Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3050	NCE3050	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	30	V	
Gate-Source Voltage	V _{GS}	±20	V	
Drain Current-Continuous	I _D	50	А	
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	35	А	
Pulsed Drain Current	I _{DM}	140	А	
Maximum Power Dissipation	P _D	60	W	
Derating factor		0.4	W/°C	
Single pulse avalanche energy (Note 5)	E _{AS}	100	mJ	
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C	

Thermal Characteristic

Electrical Characteristics (T_A=25 ℃ unless otherwise noted)

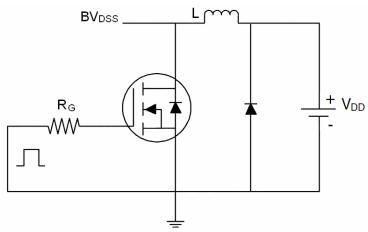
Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics			•				
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	33	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1	1.6	3	V	
Drain-Source On-State Resistance		V _{GS} =10V, I _D =25A	-	8	11	mO.	
Diani-Source On-State Resistance	R _{DS(ON)}	V _{GS} =5V, I _D =20A -		10	16	mΩ	
Forward Transconductance	G FS	V _{DS} =5V,I _D =20A	15	-	-	S	
Dynamic Characteristics (Note4)			•				
Input Capacitance	C _{lss}	\/ -45\/\/ -0\/	-	2000	-	PF	
Output Capacitance	Coss	V _{DS} =15V,V _{GS} =0V, F=1.0MHz	-	280	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.0IVID2	-	160	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t _{d(on)}		-	10	-	nS	
Turn-on Rise Time	t _r	V_{DD} =15 V , I_{D} =20 A	-	8	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =1.8 Ω	-	25	-	nS	
Turn-Off Fall Time	t _f		-	5	-	nS	
Total Gate Charge	Qg	\/ -10\/ -25A	-	32.3	-	nC	
Gate-Source Charge	Q_{gs}	V _{DS} =10V,I _D =25A, V _{GS} =10V	-	4.9	-	nC	
Gate-Drain Charge	Q_{gd}	v _{GS} -10 v	-	6.9	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =25A	-	0.85	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	50	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =50A	-	-	35	nS	
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	-	18	nC	
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)					

Notes:

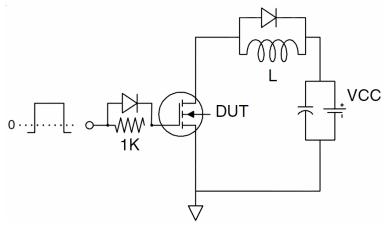
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}\text{C}\text{,V}_{DD}\text{=}15\text{V}\text{,V}_{G}\text{=}10\text{V}\text{,L=1mH,Rg=25}\Omega$

Test circuit

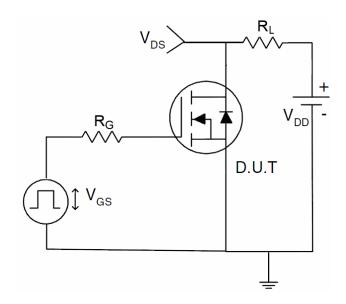
1) E_{AS} test Circuits



2) Gate charge test Circuit:



3) Switch Time Test Circuit:



Typical Electrical and Thermal Characteristics (Curves)

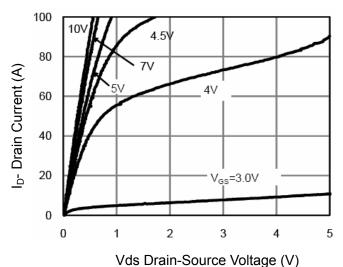


Figure 1 Output Characteristics

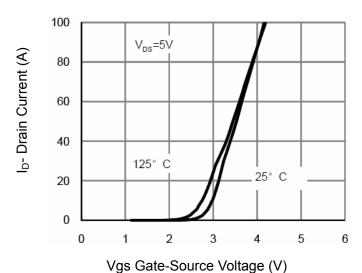


Figure 2 Transfer Characteristics

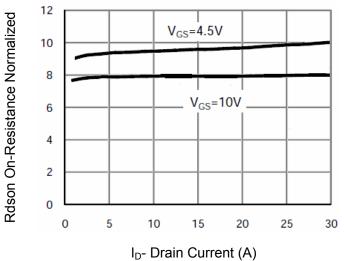


Figure 3 Rdson- Drain Current

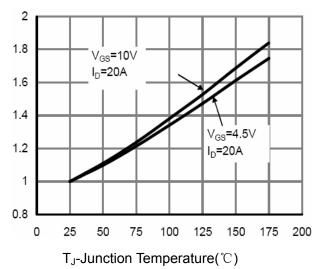


Figure 4 Rdson-JunctionTemperature

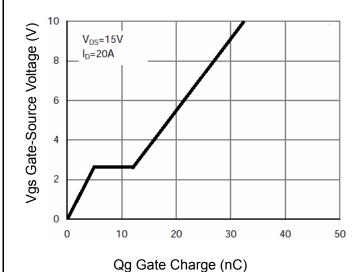


Figure 5 Gate Charge

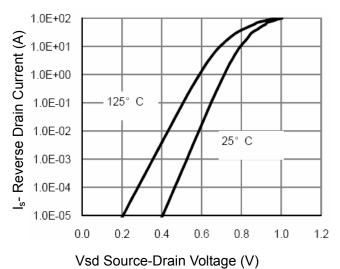


Figure 6 Source- Drain Diode Forward



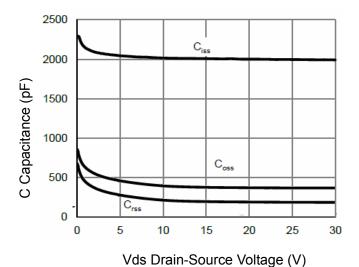
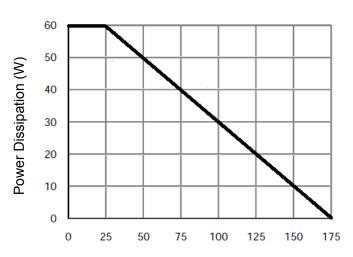


Figure 7 Capacitance vs Vds



 T_J -Junction Temperature(°C) **Figure 9 Power De-rating**

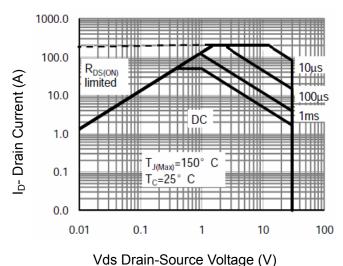


Figure 8 Safe Operation Area

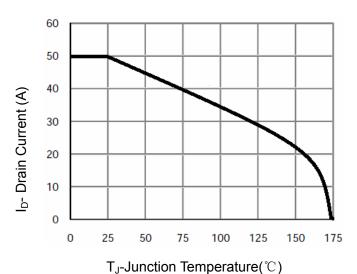


Figure 10 ID Current- Junction Temperature

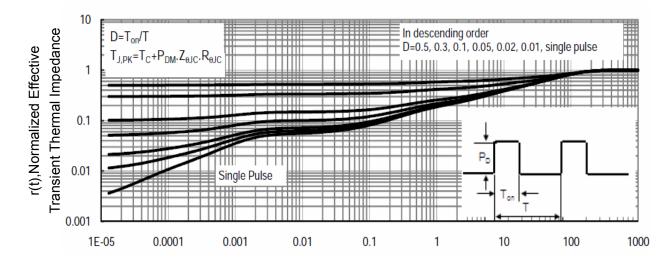
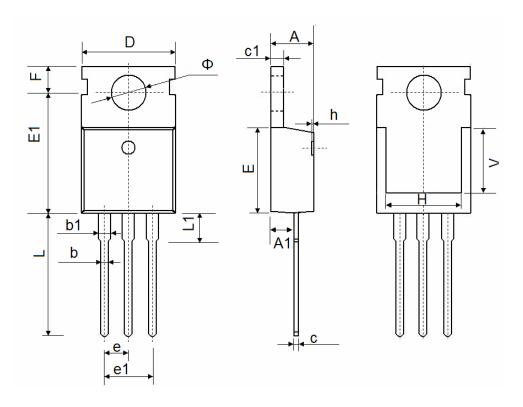


Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)

TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	

NCE3050

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